NPN Triple Diffused Planar Silicon Transistor



2SC3083

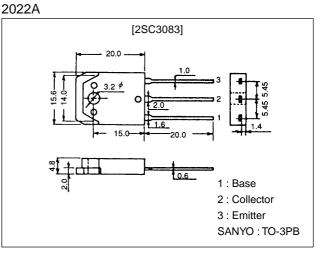
400V/6A Switching Regulator Applications

Features

- · High breakdown voltage ($V_{CBO} \ge 500V$).
- · Fast switching speed.
- \cdot Wide ASO.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		500	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	۱ _C		6	A
Collector Current (Pulse)	I _{CP}	PW≤300µs, Duty Cycle≤10%	12	A
Base Current	Ι _Β		2	A
Collector Dissipation	PC		2.5	W
		Tc=25°C	60	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =400V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =5V, I _C =0			10	μA
DC Current Gain	h _{FE} 1	$V_{CE}=5V, I_{C}=0.4A$	15*		50*	
	h _{FE} 2	V _{CE} =5V, I _C =2A	8			
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =2A, I _B =0.4A			1.0	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =2A, I _B =0.4A			1.5	V

*: The h_{FE}l of the 2SC3083 is classified as follows. When specifying the h_{FE}l rank, specify two ranks or more in principle.

15 L 30 20 M 40 30 N 50

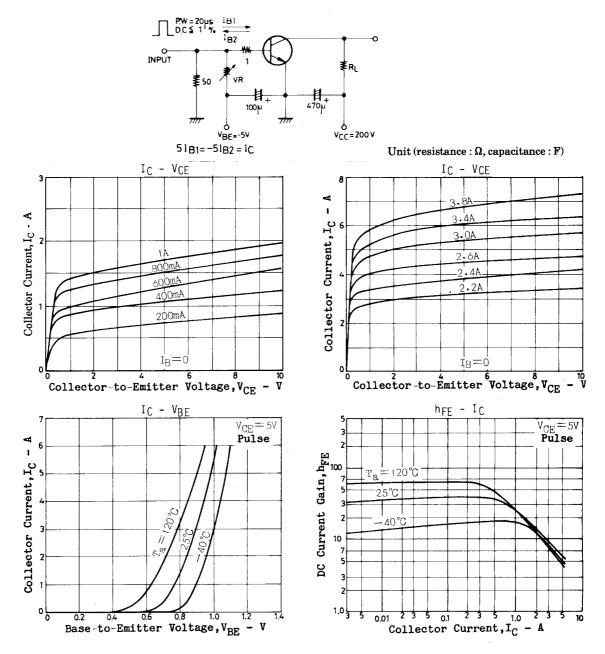
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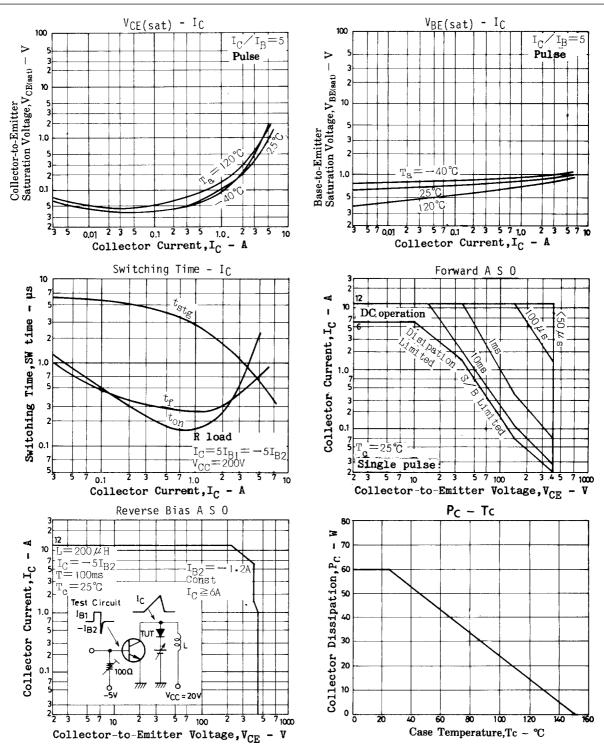
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =0.4A		20		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		40		pF
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =1mA, I _E =0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =5mA, R _{BE} =∞	400			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =1mA, I _C =0	7			V
Collector-to-Emitter Sustain Voltage	VCEO(sus)	I _C =6A, I _B =1.2A, L=50µH	400			V
Collector-to-Emitter Sustain Voltage	VCEX(sus)1	I _C =6A, I _{B1} =1.2A, L=200µH, I _{B2} =–1.2A, clamped	400			V
	VCEX(sus)2	I _C =0.75A, I _{B1} =0.15A, L=200μH, I _{B2} =–0.15A, clamped	450			V
Turn-ON Time	ton	$I_{C}{=}3A, I_{B1}{=}0.6A, I_{B2}{=}{-}0.6A, R_{L}{=}66.6\Omega, V_{CC}{=}200V$			1.0	μs
Storage Time	t _{stg}	$I_{C}{=}3A, I_{B1}{=}0.6A, I_{B2}{=}{-}0.6A, R_{L}{=}66.6\Omega, V_{CC}{=}200V$			2.5	μs
Fall Time	t _f	I_{C} =3A, I_{B1} =0.6A, I_{B2} =-0.6A, R_{L} =66.6 Ω , V_{CC} =200V			1.0	μs

Switching Time Test Circuit





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